$620 \mathrm{kHz} / 1.25 \mathrm{MHz}$ Step-up DC/DC Converter
MIC-ROFI FCTRONICS

## DESCRIPTION

The EUP2624 is a high performance current mode, PWM step-up converter with pin selectable operating frequency. With an internal $2.1 \mathrm{~A}, 170 \mathrm{~m} \Omega$ MOSFET, it can generate 12 V at up to 500 mA output current from a 5 V supply. The selectable 620 kHz and 1.25 MHz allows smaller inductors and faster transient response. An external compensation pin gives the user greater flexibility in setting loop compensation allowing the use of low ESR Ceramic output capacitors. Soft-start is controlled with an external capacitor, which determines the input current ramp rate during start-up.

When shut down, it draws $<10 \mu \mathrm{~A}$ of current and can operate down to 2.5 V input supply. These features along with 1.25 MHz switching frequency makes it an ideal device for portable equipment and TFT-LCD displays.

The EUP2624 is available in an 8-pin MSOP package. The device is specified for operation over the full $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ temperature range.

## FEATURES

- $90 \%$ Efficiency
- $2.1 \mathrm{~A}, 170 \mathrm{~m} \Omega$ Power MOSFET
- 2.5 V to 5.5 V Input Range
- Adjustable Output Voltage up to 28 V
- $620 \mathrm{kHz} / 1.25 \mathrm{MHz}$ Switching Frequency Selection
- Adjustable Soft-Start
- Internal Thermal Protection
- Small MSOP-8 package
- RoHS Compliant and $100 \%$ Lead (Pb)-Free


## APPLICATIONS

- TFT-LCD Displays
- DSL Modems
- Set-Top Boxes
- PCMCIA Cards
- Portable Equipment
- Handheld Devices


## Typical Application Circuit



Figure 1. 5V to 12V Step-Up


Figure 2. Triple Output TFT LCD Power Supply
Pin Configurations


## Pin Description

| PIN | PIN | DESCRIPTION |
| :---: | :---: | :--- |
| COMP | 1 | Compensation pin. Output of the internal error amplifier. Capacitor and resistor <br> from COMP pin to ground. |
| FB | 2 | Voltage feedback pin. Internal reference is 1.24V NOMINAL. Connect a resistor <br> divider from $V_{\text {OUT. }} . V_{\text {OUT }}=1.24 \mathrm{~V}\left(1+\mathrm{R}_{1} / \mathrm{R}_{2}\right)$. |
| $\overline{\text { SHDN }}$ | 3 | Shutdown control pin. Pull SHDN low to turn off the device. |
| GND | 4 | Analog and power ground. |
| SW | 5 | Power switch pin. Switch connected to the drain of the internal power MOSFET. |
| $\mathrm{V}_{\text {IN }}$ | 6 | Analog power input pin. |
| FSEL | 7 | Frequency select pin. When FSEL is connected to GND, switching frequency is set <br> to 620kHz. When connected to $\mathrm{V}_{\text {IN }}$, switching frequency is set to 1.25MHz |
| SS | 8 | Soft-start control pin. Connect a capacitor to control the converter start-up |

## Ordering Information

| Order Number | Package Type | Marking | Operating Temperature range |
| :---: | :---: | :---: | :---: |
| EUP2624MIR1 | MSOP-8 | xxxx | $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ |

EUP2624 $\quad$ व $\quad$ व

$\quad$| Lead Free Code |
| :--- |
| 1: Lead Free 0: Lead |
|  |
|  |
| Packing |
| R: Tape \& Reel |
| Operating temperature range |
| I: Industry Standard |
|  |
| Package Type |
|  |
| M: MSOP |

## Block Diagram



## Absolute Maximum Ratings






- Junction Temperature -------------------------------------------------------------------1500
- Lead Temp (Soldering, 10sec) --- -------------------------------------------------- $300^{\circ} \mathrm{C}$
- ESD Ratings

Human Body Model ------------------------------------------------------------------ 2kV

## Operating Conditions





## Electrical Characteristics

$\mathrm{V}_{\mathrm{IN}}=\mathrm{VSHDN}=3 \mathrm{~V} . \mathbf{T}_{\mathrm{A}}=-\mathbf{4 0 ^ { \circ }} \mathrm{C}$ to $\mathbf{8 5}{ }^{\circ} \mathrm{C}$. Typical values are at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$. Unless otherwise noted.

| Symbol | Parameter | Conditions | EUP2624 |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Min | Typ | Max. |  |
| $\mathrm{V}_{\text {IN }}$ | Input Voltage Range | $\mathrm{V}_{\text {OUT }}<18 \mathrm{~V}$ | 2.5 |  | 5.5 | V |
|  |  | $18 \mathrm{~V}<\mathrm{V}_{\text {OUT }}<24 \mathrm{~V}$ | 4.0 |  | 5.5 |  |
| UVLO | VIN Undercoltage Lockout | SW Remains off below this level. $\mathrm{V}_{\text {IN }}$ Rising, 20mV hysteresis | 1.92 | 2.15 | 2.35 | V |
| $\mathrm{I}_{\mathrm{Q}}$ | Quiescent Current | $\mathrm{FB}=2 \mathrm{~V}$ (Not Switching) |  | 0.5 | 0.8 | mA |
|  |  | $\mathrm{FB}=0 \mathrm{~V}$ ( Switching ) |  | 1.5 | 2 | mA |
|  |  | $\mathrm{V}_{\text {SHDN }}=0 \mathrm{~V}$ |  | 0.1 | 10 | uA |
| $\mathrm{V}_{\mathrm{FB}}$ | FB Regulation Voltage |  | 1.20 | 1.24 | 1.27 | V |
| $\mathrm{I}_{\mathrm{B}}$ | FB Input Bias Current | $\mathrm{V}_{\mathrm{FB}}=1.24 \mathrm{~V}$ |  | 100 | 250 | nA |
| $\begin{aligned} & \% \mathrm{~V}_{\mathrm{FB}} / \\ & \Delta \mathrm{V}_{\mathrm{IN}} \end{aligned}$ | FB Line Regulation | $2.5 \mathrm{~V} \leq \mathrm{V}_{\text {IN }} \leq 5.5 \mathrm{~V}$ |  | 0.08 | 0.15 | \%/V |
| $\begin{gathered} \hline \% \mathrm{~V}_{\mathrm{FB}} / \\ \Delta \mathrm{I}_{\mathrm{LOAD}} \\ \hline \end{gathered}$ | FB Load Regulation | $\mathrm{V}_{\text {OuT }}=8 \mathrm{~V}, \mathrm{Iload}=30 \mathrm{~mA}$ to 200 mA |  | 6.7 |  | $\mathrm{mV} / \mathrm{A}$ |
| gm | Error Amp Transconductance | $\triangle \mathrm{I}=4 \mathrm{uA}$ | 20 | 45 | 95 | umho |
| $\mathrm{A}_{\mathrm{V}}$ | Error Amp Voltage Gain |  |  | 500 |  | V/V |
| Fs | Switching Frequency | FSLCT=Ground | 500 | 620 | 740 | kHz |
|  |  | FSLCT $=\mathrm{V}_{\text {IN }}$ | 900 | 1250 | 1500 | kHz |
| $\mathrm{D}_{\text {MAX }}$ | Maximum Duty Cycle |  |  | 94 |  | \% |
| $\mathrm{I}_{\mathrm{CL}}$ | Switch Current Limit | 55\% Duty Cycle | 1.5 | 2.1 | 2.8 | A |
| $\mathrm{R}_{\text {DSON }}$ | Switch MOSFET On Resistance | $\mathrm{I}_{\text {SW }}=500 \mathrm{~mA}$ |  | 0.17 | 0.35 | $\Omega$ |
| $\mathrm{I}_{\mathrm{L}}$ | Switch Leakage Current | $\mathrm{V}_{\text {SW }}=20 \mathrm{~V}$ |  | 0.2 | 20 | uA |
| $\mathrm{I}_{\text {SS }}$ | Charge Current | $\mathrm{V}_{\text {SS }}=0 \mathrm{~V}$ | 3 | 5 | 8 | uA |
| $\mathrm{V}_{\text {IL }}$ | SHDN, FREQ Input Low Voltage |  |  |  | 0.5 | V |
| $\mathrm{V}_{\mathrm{IH}}$ | SHDN, FREQ Input High Voltage |  | 2 |  |  | V |
| $\mathrm{I}_{\text {FSLCT }}$ | FSLCT Pull Down Current |  | 2.4 | 5.5 | 8.2 | uA |

## Typical Operating Characteristics









SS Pin Current vs. Temperature




NMOS $R_{\text {DSON }}$ vs. Input Voltage


## Application Information

## Boost Converter Operations

In steady state operating and continuous conduction mode where the inductor current is continuous, the boost converter operates in two cycles. During the first cycle, the internal power FET turns on and the Schottky diode is reverse biased and cuts off the current flow to the output. The output current is supplied from the output capacitor. The voltage across the inductor is VIN and the inductor current ramps up in a rate of VIN/L, L is the inductance. The inductance is magnetized and energy is stored in the inductor. The change in inductor current is:

$$
\Delta \mathrm{I}_{\mathrm{L}}=\Delta \mathrm{T} 2 \times \frac{\mathrm{V}_{\mathrm{IN}}-\mathrm{V}_{\mathrm{OUT}}}{\mathrm{~L}}
$$

$\Delta \mathrm{T} 2=\frac{1-\mathrm{D}}{\mathrm{F}_{\mathrm{SW}}}$

For stable operation, the same amount of energy stored in the inductor must be taken out. The change in inductor current during the two cycles must be the same.

$$
\begin{aligned}
& \Delta \mathrm{I} 1+\Delta \mathrm{I} 2=0 \\
& \frac{\mathrm{D}}{\mathrm{~F}_{\mathrm{SW}}} \times \frac{\mathrm{V}_{\mathrm{IN}}}{\mathrm{~L}}+\frac{1-\mathrm{D}}{\mathrm{~F}_{\mathrm{SW}}} \times \frac{\mathrm{V}_{\mathrm{IN}}-\mathrm{V}_{\mathrm{OUT}}}{\mathrm{~L}}=0 \\
& \frac{\mathrm{~V}_{\mathrm{OUT}}}{\mathrm{~V}_{\mathrm{IN}}}=\frac{1}{1-\mathrm{D}}
\end{aligned}
$$

## Output Voltage

An external feedback resistor divider is required to divide the output voltage down to the nominal 1.24 V reference voltage. The current drawn by the resistor network should be limited to maintain the overall converter efficiency. The maximum value of the resistor network is limited by the feedback input bias current and the potential for noise being coupled into the feedback pin. Selecting $\mathrm{R}_{2}$ in the range of $10 \mathrm{k} \Omega$ to $50 \mathrm{k} \Omega$. The boost converter output voltage s determined by the relationship:

$$
\mathrm{V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{FB}} \times\left[1+\frac{\mathrm{R}_{1}}{\mathrm{R}_{2}}\right]
$$

## Inductor Selection

The inductor selection determines the output ripple voltage, transient response, output current capability, and efficiency. Its selection depends on the input voltage, output voltage, switching frequency, and maximum output current. For most applications, a $4.7 \mu \mathrm{H}$ inductor is recommended for 1.25 MHz application and a $10 \mu \mathrm{H}$ inductor is recommended for 620 kHz application. The inductor maximum DC current specification must be greater than the peak inductor current required by the regulator. The peak inductor current can be calculated:


## Output Capacitor

Low ESR capacitors should be used to minimized the output voltage ripple. Multilayer ceramic capacitors (X5R and X7R) are preferred for the output capacitors because of their lower ESR and small packages. Tantalum capacitors with higher ESR can also be used. The output ripple can be calculated as:

$$
\Delta \mathrm{V}_{\mathrm{O}}=\frac{\mathrm{I}_{\mathrm{OUT}} \times \mathrm{D}}{\mathrm{~F}_{\mathrm{SW}} \times \mathrm{C}_{\mathrm{O}}}+\mathrm{I}_{\mathrm{OUT}} \times \mathrm{ESR}
$$

Choose an output capacitor to satisfy the output ripple and load transient requirement. A $10 \mu \mathrm{~F}$ to $22 \mu \mathrm{~F}$ ceramic capacitor is suitable for most application.
For noise sensitive application, a $0.1 \mu \mathrm{~F}$ placed in parallel with the larger output capacitor is recommended to reduce the switching noise coupled from the SW switching node.

## Schottky Diode

In selecting the Schottky diode, the reverse break down voltage, forward current and forward voltage drop must be considered for optimum converter performance. The diode must be rated to handle 2 A , the current limit of the EUP2624. The breakdown voltage must exceed the maximum output voltage. Low forward voltage drop, low leakage current, and fast reverse recovery will help the converter to achieve the maximum efficiency.

The nominal VFB voltage is 1.24 V

## Input Capacitor

The value of the input capacitor depends the input and output voltages, the maximum output current, the inductor value and the noise allowed to put back on the input line. For most applications, a minimum $10 \mu \mathrm{~F}$ is required. For applications that run close to the maximum output current limit, input capacitor in the range of $22 \mu \mathrm{~F}$ to $47 \mu \mathrm{~F}$ is recommended. The EUP2624 is powered from the VIN. High frequency $0.1 \mu \mathrm{~F}$ by-pass cap is recommended to be close to the VIN pin to reduce supply line noise and ensure stable operation.

## Loop Compensation

The EUP2624 incorporates an transconductance amplifier in its feedback path to allow the user some adjustment on the transient response and better regulation. The EUP2624 uses current mode control architecture which has a fast current sense loop and a slow voltage feedback loop. The fast current feedback loop does not require any compensation. The slow voltage loop must be compensated for stable operation. The compensation network is a series RC network from COMP pin to ground. The resistor sets the high frequency integrator gain for fast transient response and the capacitor sets the integrator zero to ensure loop stability. For most applications,the compensation resistor in the range of 2 K to 30 K and the compensation capacitor in the range of 1 nF to 10 nF .

## Soft-Start

The soft-start is provided by an internal $5 \mu \mathrm{~A}$ current source charges the external CSS, the peak MOSFET current is limited by the voltage on the capacitor. This in turn controls the rising rate of the output voltage. The regulator goes through the start-up sequence as well after the SHDN pin is pulled to HI.

## Frequency Selection

The EUP2624 switching frequency can be user selected to operate at either at constant 620 kHz or 1.25 MHz . Connecting FSEL pin to ground sets the PWM switching frequency to 620 kHz . When connect FSEL high or VDD, switching frequency is set to 1.25 MHz .

## Shut-Down Control

The EUP2624 shuts down to reduce the supply current to $0.1 \mu \mathrm{~A}$ when SHDN is low. In this mode, the internal reference, error amplifier, comparators, and biasing circuitry turn off while the N-channel MOSFET is turned off. The boost converter's output is connected to IN via the external inductor and catch diode.

## Maximum Output Current

The output current capability of the EUP2624 is a function of current limit, input voltage, operating frequency, and inductor value. The output current capability is governed by the following equation:

$$
\mathrm{I}_{\mathrm{L}}=\mathrm{I}_{\mathrm{L}-\mathrm{AVG}}+\left(\mathbf{1} / \mathbf{2} \times \Delta \mathrm{I}_{\mathrm{L}}\right)
$$

Where:
$\mathrm{IL}=\mathrm{MOSET}$ current limit
$\mathrm{I}_{\mathrm{L}-\mathrm{AVG}}=$ average inductor current
$\Delta \mathrm{I}_{\mathrm{L}}=$ inductor ripple current


VDIODE $=$ Schottky diode forward voltage, typically, 0.6 V
$\mathrm{FS}=$ switching frequency, 620 KHz or 1.25 MHz

$$
\mathrm{I}_{\mathrm{L}-\mathrm{AVG}}=\frac{\mathrm{I}_{\mathrm{OUT}}}{\mathbf{1}-\mathrm{D}}
$$

$\mathrm{D}=\mathrm{MOSFET}$ turn-on ratio:

$$
\mathrm{D}=\boldsymbol{1}-\frac{\mathrm{V}_{\mathrm{IN}}}{\mathrm{v}_{\mathrm{OUT}}+\mathrm{V}_{\text {DIODE }}}
$$

## Layout Considerations

Good PC board layout and routing are required in high-frequency switching power supplies to achieve good regulation, high efficiency, and stability. It is strongly recommended that the evaluation kit PC board layouts be followed as closely as possible. Place power components as close together as possible, keeping their traces short, direct, and wide. Avoid interconnecting the ground pins of the power components using vias through an internal ground plane. Instead, keep the power components close together and route them in a "star" ground configuration using component-side coper, then connect the star ground to internal ground using multiple vias.

## Packaging Information

## MSOP-8



## NOTE

1. Package body sizes exclude mold flash and gate burrs
2. Dimension $L$ is measured in gage plane
3. Tolerance 0.10 mm unless otherwise specified
4. Controlling dimension is millimeter. Converted inch dimensions are not necessarily exact.

| SYMBOLS | DIMENSIONS IN MILLIMETERS |  |  | DIMENSIONS IN INCHES |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | NOM. | MAX. | MIN. | NOM. | MAX. |
| A | 0.81 | 0.95 | 1.10 | 0.032 | 0.0375 | 0.043 |
| A1 | 0.05 | 0.09 | 0.15 | 0.002 | 0.004 | 0.006 |
| A2 | 0.76 | 0.86 | 0.97 | 0.030 | 0.034 | 0.038 |
| b | 0.28 | 0.30 | 0.38 | 0.011 | 0.012 | 0.015 |
| C | 0.13 | 0.15 | 0.23 | 0.005 | 0.006 | 0.009 |
| D | 2.90 | 3.00 | 3.10 | 0.114 | 0.118 | 0.122 |
| E | 4.70 | 4.90 | 5.10 | 0.185 | 0.193 | 0.201 |
| E1 | 2.90 | 3.00 | 3.10 | 0.114 | 0.118 | 0.122 |
| e | ------ | 0.65 | ---- | ----- | 0.026 | ------ |
| L | 0.40 | 0.53 | 0.66 | 0.016 | 0.021 | 0.026 |
| y | ------ | ------ | 0.10 | ----- | ------ | 0.004 |
| $\theta$ | 0 | ---- | 6 | 0 | ------ | 6 |

